ACJT1235-10E 12A TRIAC

Rev.A.1.1

DESCRIPTION:

The ACJT1235-10E triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. The ACJT1235-10E embeds a TVS structure to absorb the inductive turn-off energy such as those described in the IEC 61000-4-5 standards. Package TO-263 is RoHS compliant.

MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$		
V_{DRM}/V_{RRM}	1000	V
I_{GT} / /		

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-125	
Repetitive peak off-state voltage (T_j=25)	V_{DRM}	1000	V
Repetitive peak reverse voltage (T_j=25)	V_{RRM}	1000	V
RMS on-state current ($T_C \leq$ 104)	$I_{T(RMS)}$	12	A
Non repetitive surge peak on-state current (full cycle , t_p=20ms , T_j=25)	I_{TSM}	120	A
Non repetitive surge peak on-state current (full cycle , t_p=16.6ms , T_j=25)		132	
I^2t value for fusing (t_p=10ms , T_j=25)	I^2t	72	A^2s
Critical rate of rise of on-state current (I_G=2 I_{GT} , f=100Hz , T_j=125)	dI/dt	100	A/μs
Peak gate current (t_p=20μs , T_j=125)	I_{GM}	4	A
Average gate power dissipation (T_j=125)	$P_{G(AV)}$	0.5	W
Peak gate power	P	10	W

Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.8)	V_{pp}	5	kV

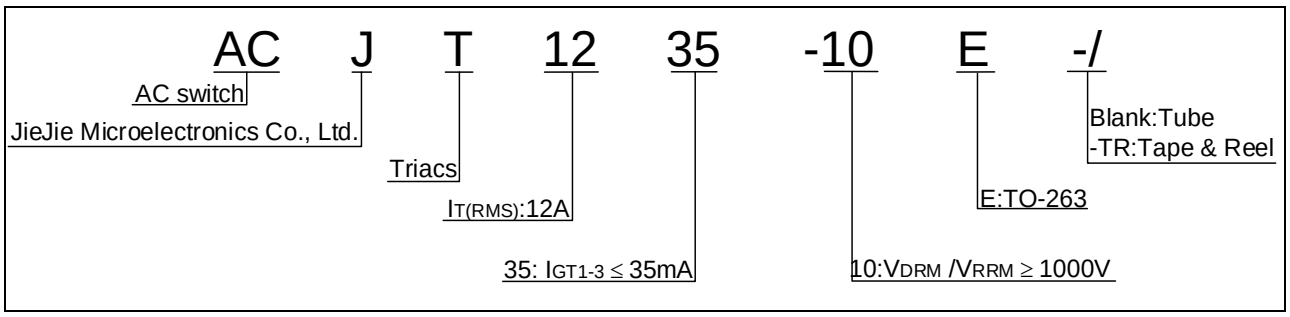
ELECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	V_D =12V R_L =33Ω	- -	MAX.	35	mA
V_{GT}		- -	MAX.	1	V
V_{GD}	V_D =V_{DRM} T_j =125 R_L =3.3kΩ	- -	MIN.	0.2	V
I_L	I_G =1.2I_{GT}	-	MAX.	50	mA
				70	
I_H	I_T =500mA		MAX.	45	mA
dV/dt	V_D=670V Gate Open T_j =125		MIN.	800	V/μs
(dI/dt)c	(dV/dt)c=20V/μs, T_j=125		MIN.	15	A/ms
t_{on}	I_G=40mA I_A=200mA I_R=20mA T_j=25		TYP.	5	μs
t_{off}				70	
V_{CL}	I_{CL}=0.1mA t_p=1ms		MIN.	1050	V

STATIC CHARACTERISTICS

Symbol	Parameter	Value(MAX.)	Unit
V_{TM}	I_{TM} =17A t_p=380μs	1.45	V
V_{TO}	Threshold voltage		

ORDERING INFORMATION



MARKING

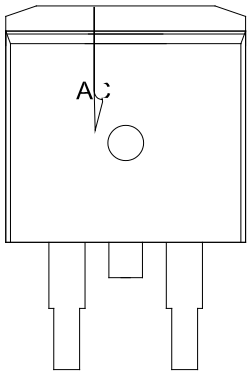


FIG.1: Maximum power dissipation versus RMS on-state current

FIG.2: RMS on-state current versus case temperature

FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

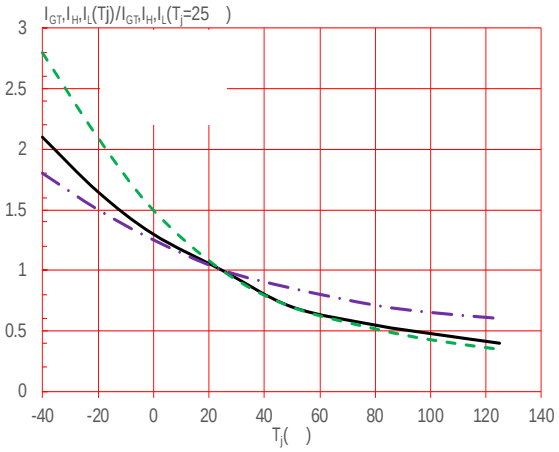
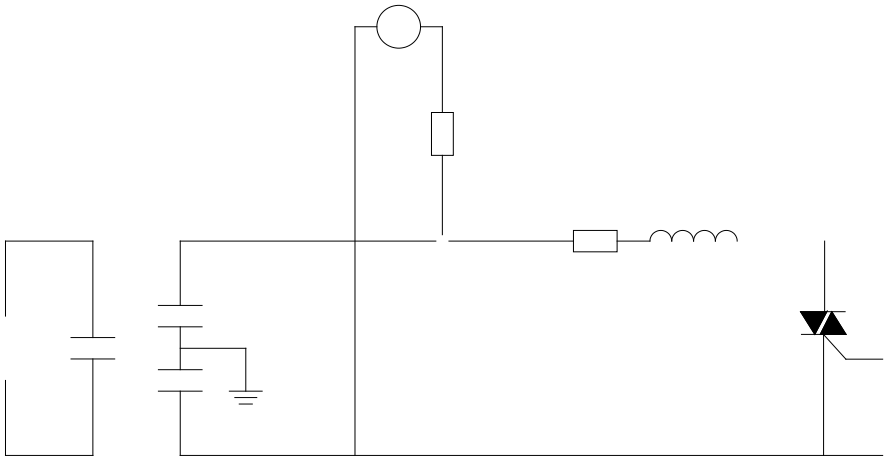


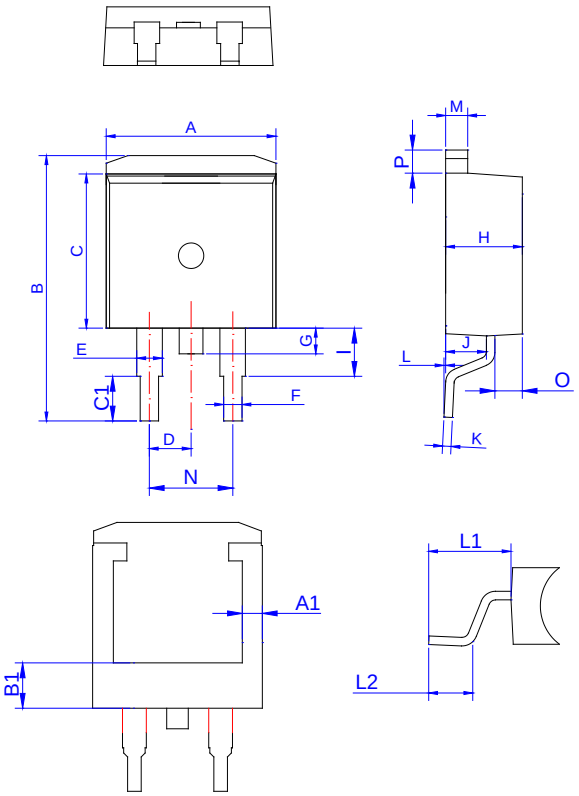
FIG.8: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



ORDERING INFORMATION

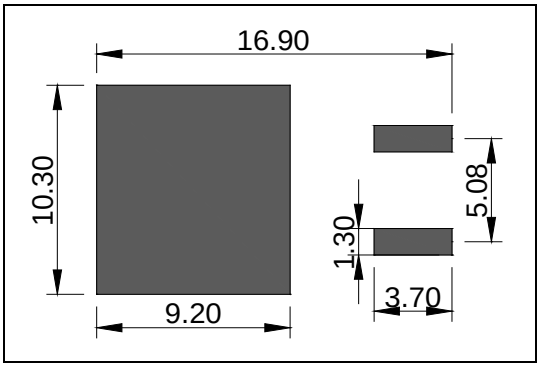
Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
ACJT1235-10E	1000	35	TO-263	50	Tube

PACKAGE MECHANICAL DATA

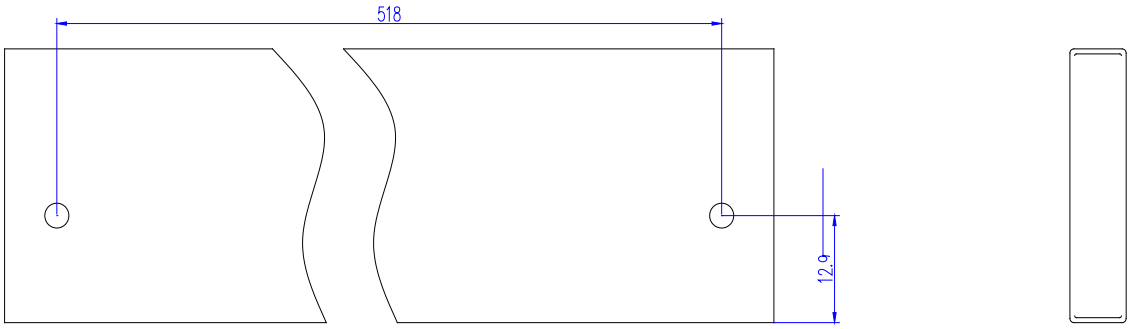


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
A1	0.80		1.20	0.031		0.047
B	14.70		15.80	0.579		0.622
B1	2.15		2.55	0.085		0.100
C	9.40		9.60	0.370		0.378
C1	2.40		2.80	0.094		0.110
D	2.40		2.70	0.094		0.106
E	1.20		1.50	0.047		0.059
F	0.75		0.85	0.029		0.033
G	1.00		1.50	0.039		0.059
H	4.40		4.70	0.173		0.185
I	1.80		2.20			
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0	0.10	0.25	0	0.004	0.010
L1	4.65		5.05	0.183		0.199
L2	1.90			0.075		
M	1.25		1.35	0.049		0.053
N	4.80		5.20			
O	1.30		1.50			
P	1.20		1.50	0.047		0.059

FOOTPRINT-TO-263 (dimensions in mm)



DELIVERY MODE



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